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Large-area X-ray detectors based on Organic and Perovskite films

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SEMICONDUCTOR PHYSICS GROUP @ DEPARTMENT OF PHYSICS AND ASTRONOMY-UNIVERSITY OF BOLOGNA







ORGANIC-HYBRID SEMICONDUCTORS FOR IONIZING RADIATION DETECTION - ADVANTAGES

Low-cost large-area printing techniques











New generation of



low cost, low power supply and mechanical flexible Thin and comformable sensor panels and patches











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THIN FILM AND LARGE AREA: WHERE?

•



- Light-weight for limited amount of materials
- Possibility to cover large surfaces at low cost
- Real-time beam monitoring
- Radiation hard to strong fluxes due to weak radiation abortion
- In-situ dose evaluation thank to conformability to human tissues



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FLEXIBLE LARGE AREA ELECTRONICS: MATERIAL PLATFORMS

High Mobility Oxide Semiconductors

e.g. $Ga_x In_y Zn_z O$



Physical/solution deposizion $\mu = 10 - 50 \text{ cm}^2/\text{Vs}$

T. Cramer et al., Sc.Adv., **4**, 63 (2018) C. Bordoni et al., APL Mater., **12**, 031106 (2024)

Organic Semiconductors

e.g. TIPS pentacene



A. Tamayo et al., Adv. Electron. Mater. 2200293 (2022) solution deposition $\mu = 1 \text{ cm}^2/\text{Vs}$

L. Basiricò et al. Nature Comm 7, 13063 (2016) I.Temino et al., Nature Comm. 11, 235 (2020)

e. g. MAPbl₃



solution deposition $\mu = 1-600 \text{ cm}^{2/}\text{Vs}$

A.Ciavatti et al., Adv. Funct. Mater. **29,** 1902346 (**2019**)



Radiation sensitive OXide Field Effect Transistors (ROXFETs)

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ORGANIC/HYBRID MATERIALS FOR X-RAY RADIATION DETECTION



Sensitivity: 10⁶ µC/Gy cm² @ 0.2V @ RT >> than polyCZT or a-Se







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L. Basiricò et al., Adv. Mater. Technol. **2020,** 2000475

8

PRINTED FLEXIBLE ELECTRONICS FOR A SUSTAINABLE FUTURE





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PRINTED FLEXIBLE ELECTRONICS FOR A SUSTAINABLE FUTURE





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Printed Hybrid Organic/Perovskite Flexible Detector



Perovskite thin films 3D blends: MAPI+PCBM

MAPbI3 NPs











1) Synthesis of **MAPbI₃ nanocrystals inks** in **low boiling point** benign **low-toxic solvent** (water and propan-2-ol)

- 2) Printing by bar coating in air
- 3) Coating with electrons acceptor (PC60BM) trap passivation
- 4) Multiple deposition steps, up to **10 μm thick film** relative high X-ray attenuated fraction (40%@40kV, 9%@150kV).



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Perovskite thin films 3D blends: MAPI+PCBM



- ightarrow 2-terminal planar device
- \rightarrow Low operation bias < 4V
- \rightarrow High sensitivity, top value up to 2270 μ C Gy⁻¹ cm⁻²
- → radiation tolerance >2 Gy and fast response time (< 50 ms)

X-ray 40kV

L. Basirico' et al *Nature Comm* (**2016**) I. Temino et al *Nature Comm* (**2020**) A.Ciavatti et al., *Adv. Funct. Mater.* (**2021**) M Verdi et al. *Adv. Mat. Interfaces* (**2023**)



Perovskite thin films 3D blends: role of carrier traps



MAPI+PCBM improved performance due to the addition of the PCBM layer:

- due to its electron acceptor properties, that passivate the traps for majority carriers in perovskite nanocrystals?
- role of traps and interfaces & PC gain effects









Simultaneous acquisition of two techniques:

- X-ray Fluorescence (XRF)
- X-ray Beam Induced Current (XBIC)

In order to understand the role of PCBM we performed simultaneously **XRF and XBIC** on sample with and without PCBM



IDB16B beamline at the ESRF-EBS synchrotron Beam spot size 50nmx50nm



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XRF vs. XBIC

XBIC



Pb XRF

- We can correlate the Pb distribution (morphology) to the current signal
- In the MAPI sample the grain boundaries are highlighted in the XBIC map
- A more uniform XBIC signal was obtained for MAPI+PCBM sample

M. Verdi, **A. Ciavatti** et al., Adv. Electron. Mater. 2201346, 2023



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22





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 On average in the samples with PCBM the current density is almost double respect to only MAPI samples



27



 On average in the samples with PCBM the current density is almost double respect to only MAPI samples



• Higher correlation between XRF and XBIC signals

$$r = \frac{\sum_{i=1}^{n} (x_i - \bar{x}) (y_i - \bar{y})}{\sqrt{\sum_{i=1}^{n} (x_i - \bar{x})^2} \sqrt{(y_i - \bar{y})^2}}$$



28



- On average in the samples with PCBM the current density is almost double respect to only MAPI samples
- PCBM creates higher current by acting as an electron sink and creating higher gain in the perovskite layer



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• PCBM passivates Traps at the grain boundaries



30

Only MAPI devices

MAPI + PCBM devices

• e⁻ • h⁺ □Trap □ e⁻ Trapped



High traps concentration at grain boundaries. Trapped minority carriers (electrons) activate a gain mechanism through holes injection from electrodes.



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HAPI + PCBM devices • e⁻ • h⁺ Trap PCBM X-ray



Only MAPI devices

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MAPI + PCBM devices • e⁻ • h⁺ Trap PCBM X-ray

- PCBM passivates the majority carrier (holes) traps
 - \rightarrow more mobile holes
 - \rightarrow general increase of gain



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HAPI + PCBM devices

- PCBM passivates the majority carrier (holes) traps
 - \rightarrow more mobile holes
 - \rightarrow general increase of gain
- PCMB as electrons acceptor
 - ightarrow subtract electrons from recombination improving holes lifetime
 - \rightarrow spatially uniform gain effect

2D layered Perovskites



35

2D layered Perovskites

$\mathbf{PEA_2PbBr_4} (\mathsf{PEA} = \mathsf{C}_6\mathsf{H}_5\mathsf{C}_2\mathsf{H}_4\mathsf{NH}_3^+)$

3D

VS.

2D

APbX₃ Organic Ha cation a (MA, FA) (I,



Halogen

anion

(I, Br, CI)

- High X-ray stopping power 10 cm⁻¹, comparable to CZT.
- High carriers diffusion length >1µm in polycrystalline films.
- Low cost, low temperature <150°C deposition from solution.
- Optoelectronic properties tuning by controlling the relative amounts of the components

 $\sim Pb$ Organic Halogen cation anion (PEA, (I, Br, CI) BA)

- High X-ray stopping power.
- Lower mobility
- Lower Ion migration
- Better stability
- Low cost, low temperature <150°C deposition from solution.
- Optoelectronic properties tuning by controlling the relative amounts of the components



2D Perovskites thin film X-ray radiation detectors



- PEA₂PbBr₄
- Easy and scalable fabrication procedure (solution deposition)



- 125 µm PET substrate
- large grains (33.5±8.3 µm) bridging the metal contacts
- Layer thickness < 1-2 μm
- very low dark current for a non-diode structure (10⁻¹³ A at 500 V mm-1 electric field), without the necessity of interlayers



2D Perovskites thin film X-ray radiation detectors



STABILITY & REPRODUCIBILITY

- Very stable to repeated pulses (300 consecutive pulses in a total of 30 minutes)
- Very stable under continuous irradiation of 10 minutes (4 Gy total dose at 80 V) Energies 40keV-150keV (mammography and CT scans).
- Same response after 80 days of storage in air not encapsulated



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Wearable wireless X-ray sensor (up to 150keV) based on 2D perovskite thin films



A.Ciavatti et al. Advanced Material Technologies (2022) L.Basirico' et al. Manuscript submitted (2024) Wearable wireless X-ray sensor (up to 150keV) based on 2D perovskite thin films



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L.Basirico' et al. Manuscript submitted (2024)

Direct detection by 3D perovskites on textiles





42

Direct detection by 3D perovskites on textiles



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FLEXIBLE X-RAY BEAM MONITOR ARRAY



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I. Fratelli et al., Advanced Science (2024), in publication

CONCLUSIONS

Flexible, lightweight, printed radiation detectors based on perovskite thin film, can effectively and directly detect ionizing radiation with ultrahigh sensitivity





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Camilla Bordoni **Giulia Napolitano**



https://site.unibo.it/semic onductor-physics/en



IRIS Ionizing radiation detectors for wearable dosimetry of space crews (2022-2025)













(2024 - 2025)



Thank you for your attention



47